



# BUK96180-100A

N-channel TrenchMOS logic level FET

Rev. 02 — 26 April 2011

Product data sheet

## 1. Product profile

### 1.1 General description

Logic level N-channel enhancement mode Field-Effect Transistor (FET) in a plastic package using TrenchMOS technology. This product has been designed and qualified to the appropriate AEC standard for use in automotive critical applications.

### 1.2 Features and benefits

- AEC Q101 compliant
- Low conduction losses due to low on-state resistance

### 1.3 Applications

- Automotive and general purpose power switching

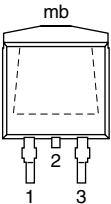
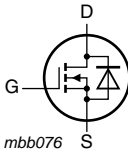
### 1.4 Quick reference data

Table 1. Quick reference data

| Symbol                 | Parameter                                    | Conditions  | Min | Typ | Max | Unit |
|------------------------|--|---|-----|-----|-----|------|
| V <sub>DS</sub>        | drain-source voltage                         | T <sub>j</sub> ≥ 25 °C; T <sub>j</sub> ≤ 175 °C   | -   | -   | 100 | V    |
| I <sub>D</sub>         | drain current                                | T <sub>mb</sub> = 25 °C   | -   | -   | 11  | A    |
| P <sub>tot</sub>       | total power dissipation                      |   | -   | -   | 54  | W    |
| Static characteristics |  |   |     |     |     |      |
| R <sub>DSon</sub>      | drain-source on-state resistance             | V <sub>GS</sub> = 10 V; I <sub>D</sub> = 5 A; T <sub>j</sub> = 25 °C  | -   | 152 | 173 | mΩ   |
|                        |  | V <sub>GS</sub> = 5 V; I <sub>D</sub> = 5 A; T <sub>j</sub> = 25 °C   | -   | 165 | 180 | mΩ   |
| Avalanche ruggedness   |  |   |     |     |     |      |
| E <sub>DS(AL)S</sub>   | non-repetitive drain-source avalanche energy | I <sub>D</sub> = 5.5 A; V <sub>sup</sub> ≤ 25 V;<br>R <sub>GS</sub> = 50 Ω; V <sub>GS</sub> = 5 V;<br>T <sub>j(init)</sub> = 25 °C; unclamped | -   | -   | 1.5 | mJ   |

## 2. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description                       | Simplified outline  | Graphic symbol  |
|-----|--------|-----------------------------------|---|---|
| 1   | G      | gate                              |  |  |
| 2   | D      | drain                             |   |   |
| 3   | S      | source                            |   |   |
| mb  | D      | mounting base; connected to drain |   |   |

**SOT404 (D2PAK)**

## 3. Ordering information

Table 3. Ordering information

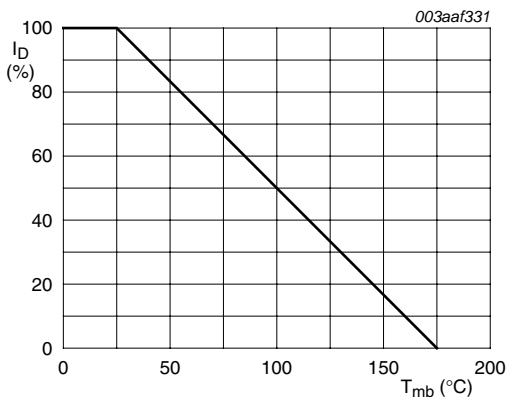
| Type number   | Package |  | Version |
|---------------|---------|--|---------|
|               | Name    | Description  |         |
| BUK96180-100A | D2PAK   | plastic single-ended surface-mounted package (D2PAK); 3 leads (one lead cropped) | SOT404  |

## 4. Limiting values

Table 4. Limiting values

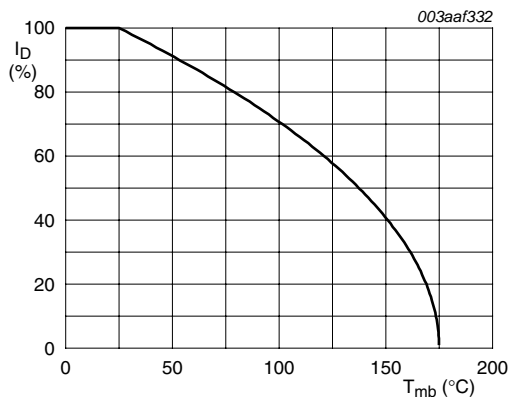
In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol                      | Parameter                                    | Conditions   | Min | Max | Unit |
|-----------------------------|--|--|-----|-----|------|
| $V_{DS}$                    | drain-source voltage                         | $T_j \geq 25\text{ °C}$ ; $T_j \leq 175\text{ °C}$   | -   | 100 | V    |
| $V_{DGR}$                   | drain-gate voltage                           | $R_{GS} = 20\text{ k}\Omega$   | -   | 100 | V    |
| $V_{GS}$                    | gate-source voltage                          |  | -15 | 15  | V    |
| $I_D$                       | drain current                                | $T_{mb} = 25\text{ °C}$  | -   | 11  | A    |
|                             |  | $T_{mb} = 100\text{ °C}$   | -   | 7.7 | A    |
| $I_{DM}$                    | peak drain current                           | $T_{mb} = 25\text{ °C}$ ; pulsed   | -   | 44  | A    |
| $P_{tot}$                   | total power dissipation                      | $T_{mb} = 25\text{ °C}$  | -   | 54  | W    |
| $T_{stg}$                   | storage temperature                          |  | -55 | 175 | °C   |
| $T_j$                       | junction temperature                         |  | -55 | 175 | °C   |
| <b>Source-drain diode</b>   |  |  |     |     |      |
| $I_S$                       | source current                               | $T_{mb} = 25\text{ °C}$  | -   | 11  | A    |
| $I_{SM}$                    | peak source current                          | pulsed; $T_{mb} = 25\text{ °C}$  | -   | 44  | A    |
| <b>Avalanche ruggedness</b> |  |  |     |     |      |
| $E_{DS(AL)S}$               | non-repetitive drain-source avalanche energy | $I_D = 5.5\text{ A}$ ; $V_{sup} \leq 25\text{ V}$ ; $R_{GS} = 50\text{ }\Omega$ ; $V_{GS} = 5\text{ V}$ ; $T_{j(init)} = 25\text{ °C}$ ; unclamped | -   | 1.5 | mJ   |



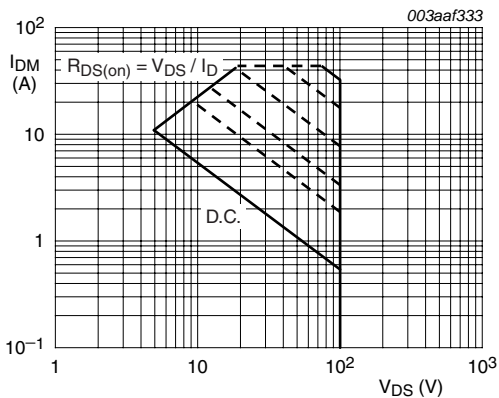
$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}\text{C})}} \times 100\%$$

Fig 1. Normalized total power dissipation as a function of mounting base temperature



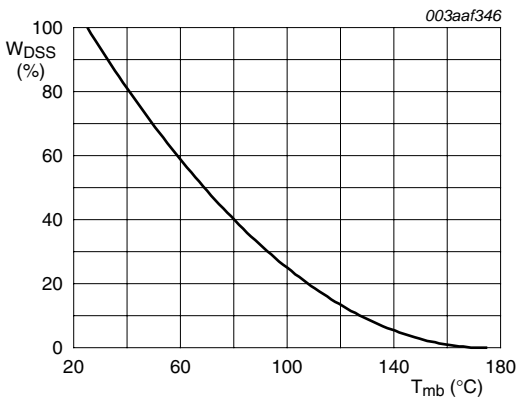
$$I_{der} = \frac{I_D}{I_{D(25^{\circ}\text{C})}} \times 100\%$$

Fig 2. Normalized continuous drain current as a function of mounting base temperature



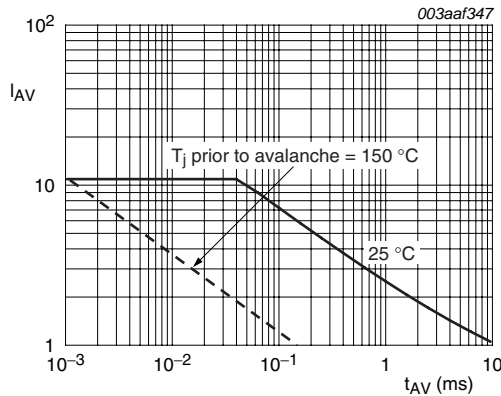
$T_{mb} = 25^{\circ}\text{C}$ ;  $I_{DM}$  is single pulse

Fig 3. Safe operating area; continuous and peak drain currents as a function of drain-source voltage



$I_D = 75\text{ A}$

Fig 4. Normalised drain-source non-repetitive avalanche energy as a function of mounting-base temperature



unclamped inductive load

Fig 5. Single-shot avalanche rating; avalanche current as a function of avalanche period

5. Thermal characteristics

Table 5. Thermal characteristics

| Symbol         | Parameter   | Conditions                    | Min | Typ | Max | Unit |
|----------------|---|-------------------------------|-----|-----|-----|------|
| $R_{th(j-mb)}$ | thermal resistance from junction to mounting base |                               | -   | -   | 2.8 | K/W  |
| $R_{th(j-a)}$  | thermal resistance from junction to ambient       | minimum footprint ; FR4 board | -   | 50  | -   | K/W  |

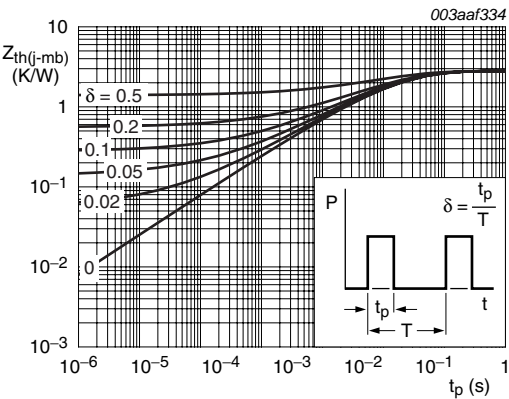


Fig 6. Transient thermal impedance from junction to mounting base as a function of pulse duration

## 6. Characteristics

Table 6. Characteristics

| Symbol                  | Parameter                        | Conditions  | Min | Typ  | Max | Unit |
|-------------------------|----------------------------------|---|-----|------|-----|------|
| Static characteristics  |                                  |   |     |      |     |      |
| V <sub>(BR)DSS</sub>    | drain-source breakdown voltage   | I <sub>D</sub> = 0.25 mA; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C   | 100 | -    | -   | V    |
|                         |                                  | I <sub>D</sub> = 0.25 mA; V <sub>GS</sub> = 0 V; T <sub>j</sub> = -55 °C  | 89  | -    | -   | V    |
| V <sub>GS(th)</sub>     | gate-source threshold voltage    | I <sub>D</sub> = 1 mA; V <sub>DS</sub> = V <sub>GS</sub> ; T <sub>j</sub> = -55 °C  | -   | -    | 2.3 | V    |
|                         |                                  | I <sub>D</sub> = 1 mA; V <sub>DS</sub> = V <sub>GS</sub> ; T <sub>j</sub> = 25 °C   | 1   | 1.5  | 2   | V    |
|                         |                                  | I <sub>D</sub> = 1 mA; V <sub>DS</sub> = V <sub>GS</sub> ; T <sub>j</sub> = 175 °C  | 0.5 | -    | -   | V    |
| I <sub>DSS</sub>        | drain leakage current            | V <sub>DS</sub> = 100 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 175 °C   | -   | -    | 500 | µA   |
|                         |                                  | V <sub>DS</sub> = 100 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C  | -   | 0.05 | 10  | µA   |
| I <sub>GSS</sub>        | gate leakage current             | V <sub>GS</sub> = 10 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C   | -   | 2    | 100 | nA   |
|                         |                                  | V <sub>GS</sub> = -10 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C  | -   | 2    | 100 | nA   |
| R <sub>DSon</sub>       | drain-source on-state resistance | V <sub>GS</sub> = 5 V; I <sub>D</sub> = 5 A; T <sub>j</sub> = 175 °C  | -   | -    | 450 | mΩ   |
|                         |                                  | V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 5 A; T <sub>j</sub> = 25 °C   | -   | 170  | 200 | mΩ   |
|                         |                                  | V <sub>GS</sub> = 10 V; I <sub>D</sub> = 5 A; T <sub>j</sub> = 25 °C  | -   | 152  | 173 | mΩ   |
|                         |                                  | V <sub>GS</sub> = 5 V; I <sub>D</sub> = 5 A; T <sub>j</sub> = 25 °C   | -   | 165  | 180 | mΩ   |
| Dynamic characteristics |                                  |   |     |      |     |      |
| C <sub>iss</sub>        | input capacitance                | V <sub>GS</sub> = 0 V; V <sub>DS</sub> = 25 V; f = 1 MHz; T <sub>j</sub> = 25 °C  | -   | 464  | 619 | pF   |
| C <sub>oss</sub>        | output capacitance               |   | -   | 60   | 72  | pF   |
| C <sub>rss</sub>        | reverse transfer capacitance     |   | -   | 37   | 50  | pF   |
| t <sub>d(on)</sub>      | turn-on delay time               | V <sub>DS</sub> = 30 V; R <sub>L</sub> = 1.2 Ω; V <sub>GS</sub> = 5 V; R <sub>G(ext)</sub> = 10 Ω; T <sub>j</sub> = 25 °C       | -   | 9    | 20  | ns   |
| t <sub>r</sub>          | rise time                        |   | -   | 112  | 157 | ns   |
| t <sub>d(off)</sub>     | turn-off delay time              |   | -   | 18   | 27  | ns   |
| t <sub>f</sub>          | fall time                        |   | -   | 25   | 38  | ns   |
| L <sub>D</sub>          | internal drain inductance        | measured from drain lead 6 mm from package to centre of die   | -   | 4.5  | -   | nH   |
|                         |                                  | measured from upper edge of drain tab to centre of die  | -   | 2.5  | -   | nH   |
| L <sub>S</sub>          | internal source inductance       | measured from source lead to source bond pad  | -   | 7.5  | -   | nH   |
| Source-drain diode      |                                  |   |     |      |     |      |
| V <sub>SD</sub>         | source-drain voltage             | I <sub>S</sub> = 5 A; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C   | -   | 0.85 | 1.2 | V    |
|                         |                                  | I <sub>S</sub> = 11 A; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C  | -   | 1.1  | -   | V    |
| t <sub>rr</sub>         | reverse recovery time            | I <sub>S</sub> = 11 A; dI <sub>S</sub> /dt = -100 A/µs; V <sub>GS</sub> = -10 V; V <sub>DS</sub> = 30 V; T <sub>j</sub> = 25 °C | -   | 49   | -   | ns   |
| Q <sub>r</sub>          | recovered charge                 |   | -   | 0.13 | -   | µC   |

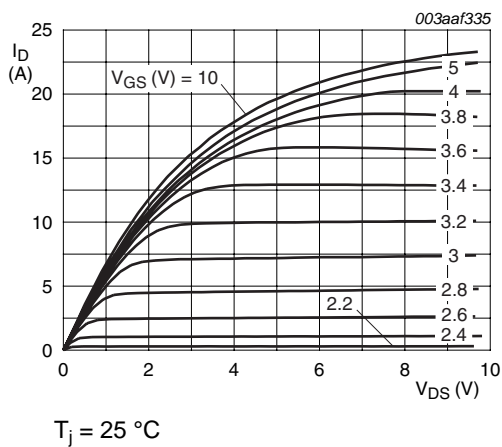


Fig 7. Output characteristics: drain current as a function of drain-source voltage; typical values

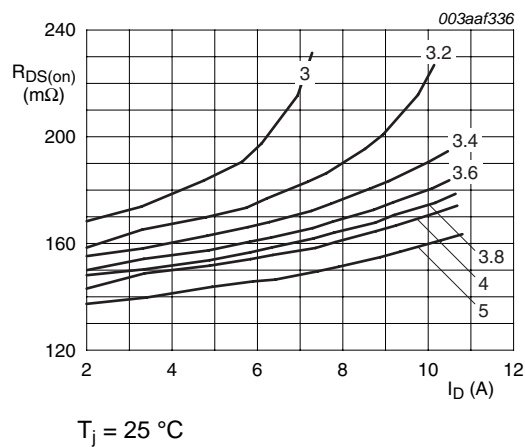


Fig 8. Drain-source on-state resistance as a function of drain current; typical values

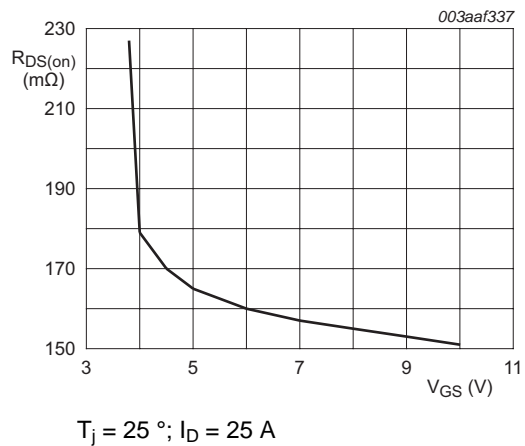


Fig 9. Drain-source on-state resistance as a function of gate-source voltage; typical values

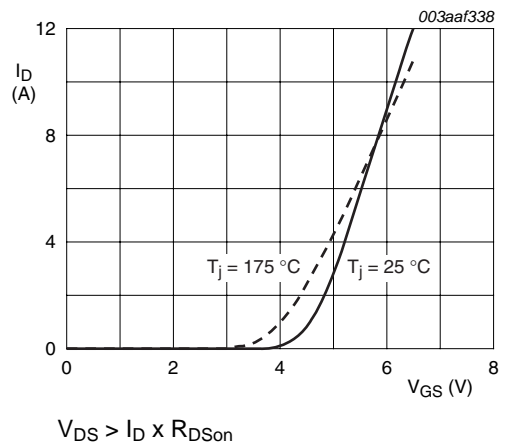


Fig 10. Transfer characteristics: drain current as a function of gate-source voltage; typical values

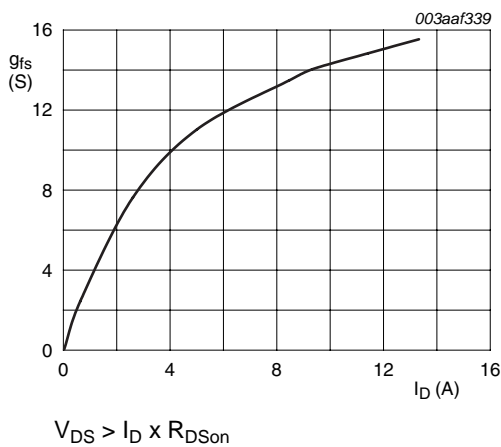


Fig 11. Forward transconductance as a function of drain current; typical values

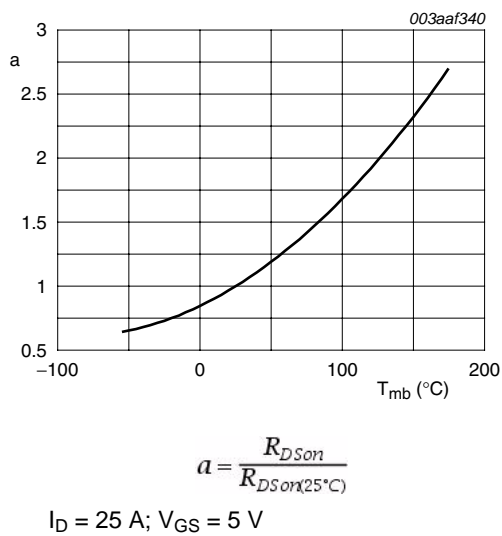


Fig 12. Normalized drain-source on-state resistance factor as a function of junction temperature

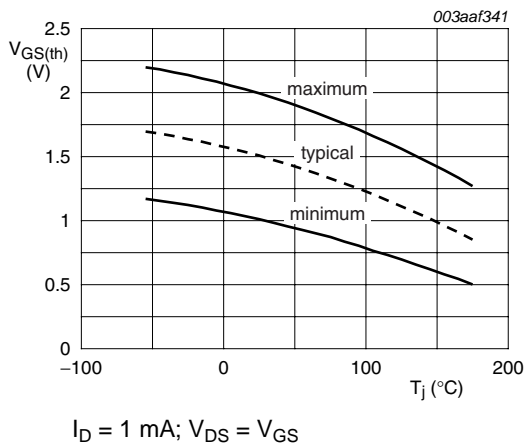


Fig 13. Gate-source threshold voltage as a function of junction temperature

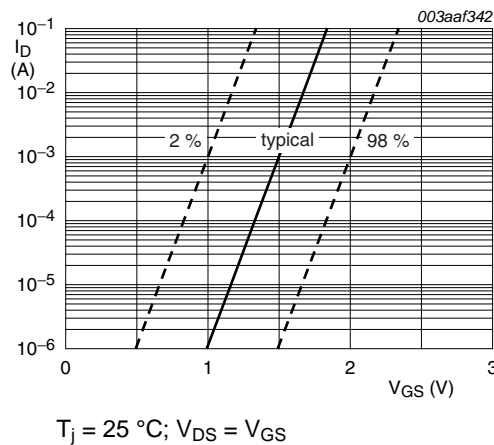


Fig 14. Sub-threshold drain current as a function of gate-source voltage

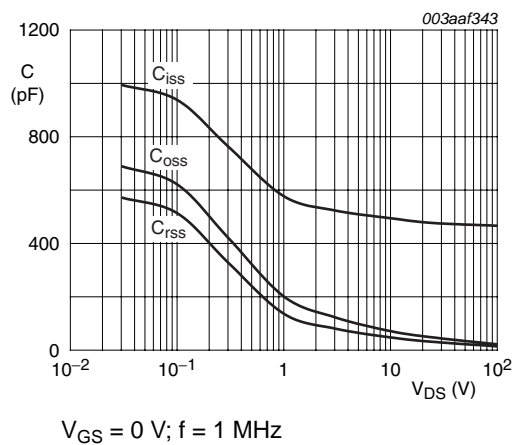


Fig 15. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

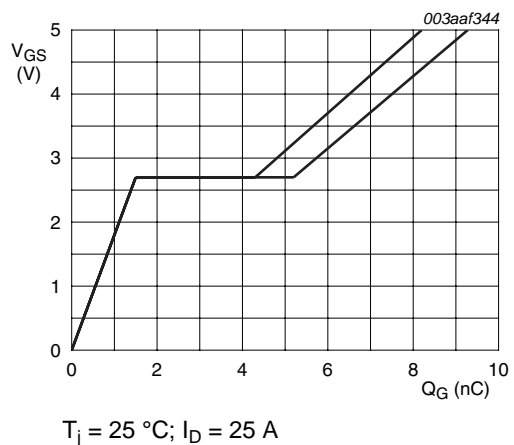


Fig 16. Gate-source voltage as a function of gate charge; typical values

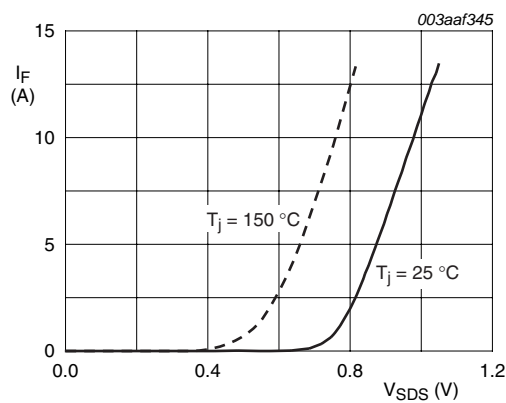


Fig 17. Source (diode forward) current as a function of source-drain (diode forward) voltage; typical values



7. Package outline

Plastic single-ended surface-mounted package (D2PAK); 3 leads (one lead cropped) SOT404

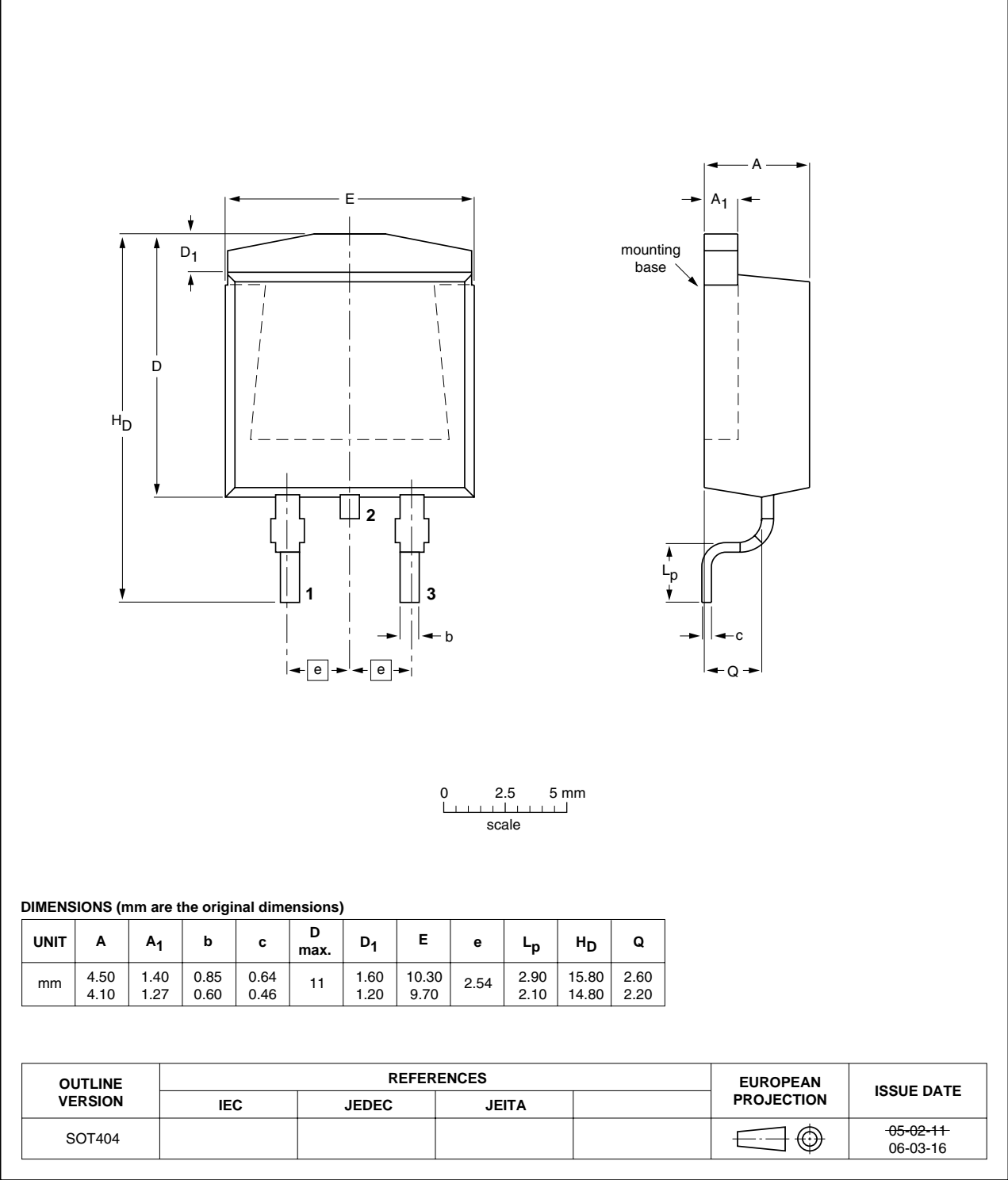


Fig 18. Package outline SOT404 (D2PAK)

## 8. Revision history

Table 7. Revision history

| Document ID             | Release date  | Data sheet status     | Change notice | Supersedes              |
|-------------------------|---|-----------------------|---------------|-------------------------|
| BUK96180-100A v.2       | 20110426  | Product data sheet    | -             | BUK95180_96180-100A v.1 |
| Modifications:          | <ul style="list-style-type: none"><li>• The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors.</li><li>• Legal texts have been adapted to the new company name where appropriate.</li><li>• Type number BUK96180-100A separated from data sheet BUK95180_96180-100A v.1.</li></ul> |                       |               |                         |
| BUK95180_96180-100A v.1 | 20000501  | Product specification | -             | -                       |

## 9. Legal information

### 9.1 Data sheet status

| Document status <sup>[1] [2]</sup> | Product status <sup>[3]</sup> | Definition  |
|------------------------------------|-------------------------------|---|
| Objective [short] data sheet       | Development                   | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet     | Qualification                 | This document contains data from the preliminary specification.                       |
| Product [short] data sheet         | Production                    | This document contains the product specification.                                     |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Помощь Конструкторского Отдела и консультации квалифицированных инженеров;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Поставка электронных компонентов под контролем ВП;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- При необходимости вся продукция военного и аэрокосмического назначения проходит испытания и сертификацию в лаборатории (по согласованию с заказчиком);
- Поставка специализированных компонентов военного и аэрокосмического уровня качества (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Actel, Aeroflex, Peregrine, VPT, Syfer, Eurofarad, Texas Instruments, MS Kennedy, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Компания «Океан Электроники» является официальным дистрибьютором и эксклюзивным представителем в России одного из крупнейших производителей разъемов военного и аэрокосмического назначения «JONHON», а так же официальным дистрибьютором и эксклюзивным представителем в России производителя высокотехнологичных и надежных решений для передачи СВЧ сигналов «FORSTAR».



## JONHON

«JONHON» (основан в 1970 г.)

Разъемы специального, военного и аэрокосмического назначения:

(Применяются в военной, авиационной, аэрокосмической, морской, железнодорожной, горно- и нефтедобывающей отраслях промышленности)

«FORSTAR» (основан в 1998 г.)

ВЧ соединители, коаксиальные кабели,  
кабельные сборки и микроволновые компоненты:

(Применяются в телекоммуникациях гражданского и специального назначения, в средствах связи, РЛС, а так же военной, авиационной и аэрокосмической отраслях промышленности).



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